

élantec

EL2126C Ultra-Low Noise, Low Power, Wideband Amplifier

Features

- Voltage noise of only $1.3nV/\sqrt{Hz}$
- Current noise of only $1.2pA/\sqrt{Hz}$
- 200µV offset voltage
- 100MHz -3dB BW for $A_V=10$
- Very low supply current 4.7mA
- SOT-23 package
- $\pm 2.5V$ to $\pm 15V$ operation

Applications

- Ultrasound input amplifiers
- Wideband instrumentation
- Communication equipment
- AGC & PLL active filters
- · Wideband sensors

Ordering Information

| Part No | Package | Tape & Reel | Outline # |
|--------------|---------------|----------------|-----------|
| EL2126CW-T7 | 5-Pin SOT-23* | 7" | MDP0038 |
| EL2126CW-T13 | 5-Pin SOT-23* | 13" | MDP0038 |
| EL2126CS | 8-Pin SO | - | MDP0027 |
| EL2126CS-T7 | 8-Pin SO | 7" | MDP0027 |
| EL2126CS-T13 | 8-Pin SO | 13" | MDP0027 |

*EL2126CW symbol is .Gxxx where xxx represents date code

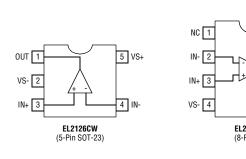
General Description

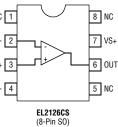
The EL2126C is an ultra-low noise, wideband amplifier that runs on half the supply current of competitive parts. It is intended for use in systems such as ultrasound imaging where a very small signal needs to be amplified by a large amount without adding significant noise. Its low power dissipation enables it to be packaged in the tiny SOT-23 package, which further helps systems where many input channels create both space and power dissipation problems.

The EL2126C is stable for gains of 10 and greater and uses traditional voltage feedback. This allows the use of reactive elements in the feedback loop, a common requirement for many filter topologies. It operates from $\pm 2.5V$ to $\pm 15V$ supplies and is available in the 5-pin SOT-23 and 8-pin SO packages.

The EL2126C is fabricated in Elantec's proprietary complementary bipolar process, and is specified for operation over the full -40°C to $+85^{\circ}$ C temperature range.

Connection Diagrams





CAUTION: These devices are sensitive to electrostatic discharge; follow proper IC Handling Procedures. 1-888-ELANTEC or 408-945-1323 | Intersil (and design) is a registered trademark of Intersil Americas Inc. Elantec ® is a registered trademark of Elantec Semiconductor, Inc. Copyright © Intersil Americas Inc. 2002. All Rights Reserved

EL2126C Ultra-Low Noise, Low Power, Wideband Amplifier

Absolute Maximum Ratings (TA = 25°C)

| V_{S} + to V_{S} - | 33V | Operating 7 |
|---------------------------|--|-------------|
| Continuous Output Current | 40mA | Storage Ter |
| Any Input | $V_{S}\text{+}$ - 0.3V to $V_{S}\text{-}$ + 0.3V | Maximum |
| Power Dissipation | See Curves | |
| 1 | | |

Derating Temperature torage Temperature Jaximum Die Junction Temperature -40°C to +85°C -60°C to +150°C +150°C

Important Note:

All parameters having Min/Max specifications are guaranteed. Typ values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$

Electrical Characteristics

 $V_{S^+}=+5V, V_{S^-}=-5V, T_A=25^\circ C, R_F=180\Omega, R_G=20\Omega, R_L=500\Omega \text{ unless otherwise specified.}$

| Parameter | Description | Conditions | Min | Тур | Max | Unit |
|--------------------|---|--|------|-------|------|--------|
| DC Perform | ance | · | | | | |
| V _{OS} | Input Offset Voltage (SO8) | | | 0.2 | 2 | mV |
| | Input Offset Voltage (SOT23-5) | | | | 3 | mV |
| T _{CVOS} | Offset Voltage Temperature Coefficient | | | 17 | | µV/°C |
| IB | Input Bias Current | | -10 | -7 | | μΑ |
| Ios | Input Bias Current Offset | | | 0.06 | 0.6 | μΑ |
| T _{CIB} | Input Bias Current Temperature Coefficient | | | 0.013 | | µA/°C |
| CIN | Input Capacitance | | | 2.2 | | pF |
| Avol | Open Loop Gain | $V_{O} = -2.5V$ to $+2.5V$ | 80 | 87 | | dB |
| PSRR | Power Supply Rejection Ratio ^[1] | | 80 | 100 | | dB |
| CMRR | Common Mode Rejection Ratio | at CMIR | 75 | 106 | | dB |
| CMIR | Common Mode Input Range | | -4.6 | | 3.8 | V |
| VOUTH | Positive Output Voltage Swing | No load, $R_F = 1k\Omega$ | 3.8 | 3.8 | | V |
| VOUTL | Negative Output Voltage Swing | No load, $R_F = 1k\Omega$ | | -4 | -3.9 | V |
| V _{OUTH2} | Positive Output Voltage Swing | $R_L = 100\Omega$ | 3.2 | 3.45 | | V |
| V _{OUTL2} | Negative Output Voltage Swing | $R_L = 100\Omega$ | | -3.5 | -3.2 | V |
| IOUT | Output Short Circuit Current ^[2] | | 80 | 100 | | mA |
| I _{SY} | Supply Current | | | 4.7 | 5.5 | mA |
| AC Perform | ance - $R_G = 20\Omega$, $C_L = 3pF$ | · | | | | |
| BW | -3dB Bandwidth, $R_L = 500\Omega$ | | | 100 | | MHz |
| BW $\pm 0.1 dB$ | $\pm 0.1 dB$ Bandwidth, $R_L = 500 \Omega$ | | | 17 | | MHz |
| $BW \pm 1 dB$ | $\pm 1 dB$ Bandwidth, $R_L = 500 \Omega$ | | | 80 | | MHz |
| Peaking | Peaking, $R_L = 500\Omega$ | | | 0.6 | | dB |
| SR | Slew Rate | $V_{OUT} = 2V_{PP}$, measured at 20% to 80% | 80 | 110 | | V/µs |
| OS | Overshoot, 4Vpk-pk Output Square | Positive | | 2.8 | | % |
| | Wave | Negative | | -7 | | % |
| ts | Settling Time to 0.1% of ±1V Pulse | | | 51 | | ns |
| V _N | Voltage Noise Spectral Density | | | 1.3 | | nV/√Hz |
| I _N | Current Noise Spectral Density | | | 1.2 | | pA/√Hz |
| HD2 | 2nd Harmonic Distortion ^[3] | | | -70 | | dBc |
| HD3 | 3rd Harmonic Distortion [3] | | | -70 | | dBc |

1. Measured by moving the supplies from $\pm 4V$ to $\pm 6V$

2. Pulse test only and using a 10Ω load

3. Frequency = 1MHz, V_{OUT} = 2Vpk-pk, into 500 Ω and 5pF load

Electrical Characteristics

 $V_{S^+}=+15V,\,V_{S^-}=-15V,\,T_A=25^\circ C,\,R_F=180\Omega,\,R_G=20\Omega,\,R_L=500\Omega\text{ unless otherwise specified.}$

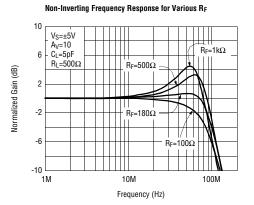
| Parameter | Description | Conditions | Min | Тур | Max | Unit |
|--------------------|---|-----------------------------------|-------|-------|-------|--------|
| DC Performa | ance | | | | | |
| V _{OS} | Input Offset Voltage (SO8) | | | 0.5 | 3 | mV |
| | Input Offset Voltage (SOT23-5) | | | | 3 | mV |
| T _{CVOS} | Offset Voltage Temperature Coefficient | | | 4.5 | | μV/°C |
| IB | Input Bias Current | | -10 | -7 | | μΑ |
| I _{OS} | Input Bias Current Offset | | | 0.12 | 0.7 | μΑ |
| T _{CIB} | Input Bias Current Temperature Coefficient | | | 0.016 | | µA/°C |
| CIN | Input Capacitance | | | 2.2 | | pF |
| A _{VOL} | Open Loop Gain | | 80 | 90 | | dB |
| PSRR | Power Supply Rejection Ratio ^[1] | | 65 | 80 | | dB |
| CMRR | Common Mode Rejection Ratio | at CMIR | 70 | 85 | | dB |
| CMIR | Common Mode Input Range | | -14.6 | | 13.8 | V |
| V _{OUTH} | Positive Output Voltage Swing | No load, $R_F = 1k\Omega$ | 13.6 | 13.7 | | V |
| VOUTL | Negative Output Voltage Swing | No load, $R_F = 1k\Omega$ | | -13.8 | -13.7 | V |
| V _{OUTH2} | Positive Output Voltage Swing | $R_L = 100\Omega, R_F = 1k\Omega$ | 10.2 | 11.2 | | V |
| V _{OUTL2} | Negative Output Voltage Swing | $R_L = 100\Omega, R_F = 1k\Omega$ | | -10.3 | -9.5 | V |
| I _{OUT} | Output Short Circuit Current ^[2] | | 140 | 220 | | mA |
| I _{SY} | Supply Current | | | 5 | 6 | mA |
| AC Performa | ance - $\mathbf{R}_{\mathbf{G}} = 20\Omega, \mathbf{C}_{\mathbf{L}} = 3\mathbf{pF}$ | • | | | | |
| BW | -3dB Bandwidth, $R_L = 500\Omega$ | | | 135 | | MHz |
| BW ± 0.1 dB | ± 0.1 dB Bandwidth, $R_L = 500\Omega$ | | | 26 | | MHz |
| $BW \pm 1 dB$ | ± 1 dB Bandwidth, R _L = 500 Ω | | | 60 | | MHz |
| Peaking | Peaking, $R_L = 500\Omega$ | | | 2.1 | | dB |
| SR | Slew Rate (±2.5V Square Wave, Mea- sured 25%-75%) | | 130 | 150 | | V/µS |
| OS | Overshoot, 4Vpk-pk Output Square | Positive | | 1.6 | | % |
| | Wave | Negative | | -4.4 | | % |
| T _S | Settling Time to 0.1% of ±1V Pulse | | | 48 | | ns |
| V _N | Voltage Noise Spectral Density | | | 1.4 | | nV/√Hz |
| I _N | Current Noise Spectral Density | | | 1.1 | | pA/√Hz |
| HD2 | 2nd Harmonic Distortion [3] | | | -72 | | dBc |
| HD3 | 3rd Harmonic Distortion [3] | | | -73 | | dBc |

1. Measured by moving the supplies from $\pm 13.5V$ to $\pm 16.5V$

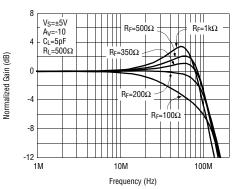
2. Pulse test only and using a 10Ω load

3. Frequency = 1MHz, $V_{OUT} = 2$ Vpk-pk, into 500Ω and 5pF load

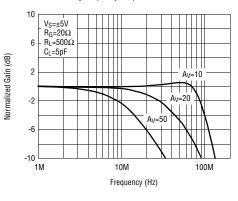
Ultra-Low Noise, Low Power, Wideband Amplifier



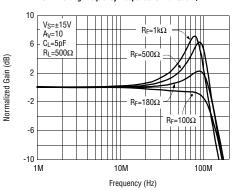
Inverting Frequency Response for Various R_F



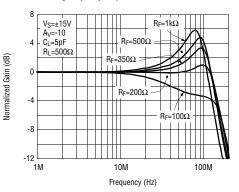
Non-Inverting Frequency Response for Various Gain



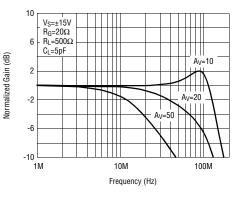
Non-Inverting Frequency Response for Various R_F



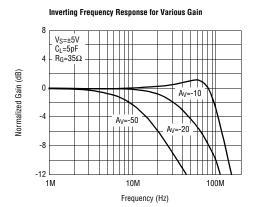
Inverting Frequency Response for Various RF

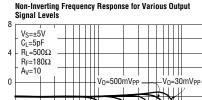


Non-Inverting Frequency Response for Various Gain

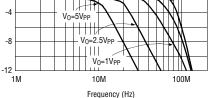


Typical Performance Curves





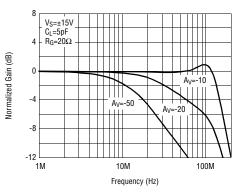
Normalized Gain (dB)



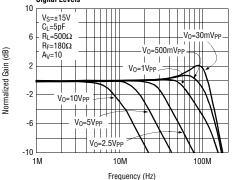
Inverting Frequency Response for Various Output Signal

Levels 8 V_S=±5V C_L=5pF V₀=500mV_{PP} 4 $R_1 = 500\Omega$ 1111 Vo=30mVPP R_F=350Ω Vo=1VPP Normalized Gain (dB) $A_V = 10$ 0 V0=3.4VPP -4 V0=2.5VPP -8 -12 1M 10M 100M Frequency (Hz)

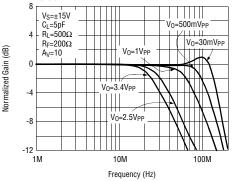
Inverting Frequency Response for Various R_F



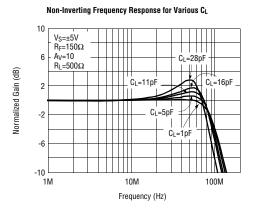
Non-Inverting Frequency Response for Various Output Signal Levels



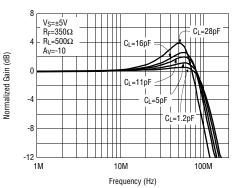
Inverting Frequency Response for Various Output Signal Levels



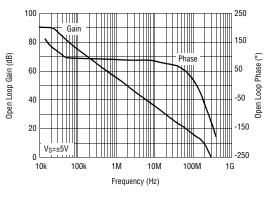
Ultra-Low Noise, Low Power, Wideband Amplifier



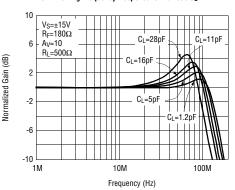
Inverting Frequency Response for Various CL



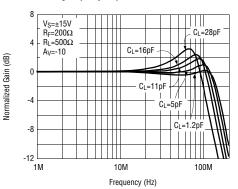
Open Loop Gain/Phase

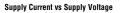


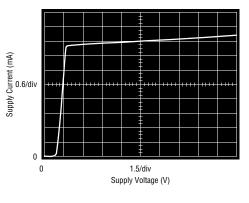
Non-Inverting Frequency Response for Various CL



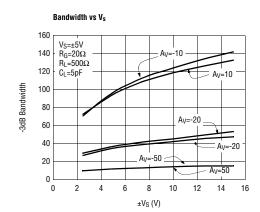
Inverting Frequency Response for Various CL



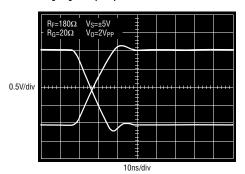




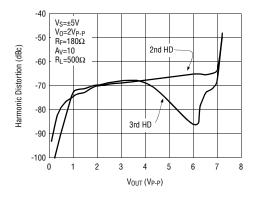
Typical Performance Curves

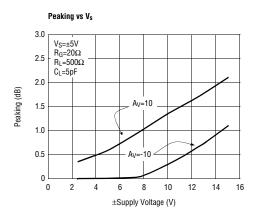


Large Signal Step Response

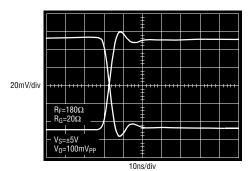




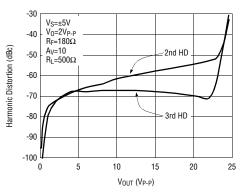




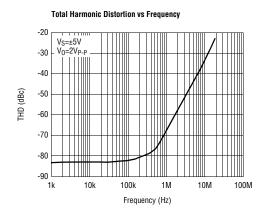
Small Signal Step Response



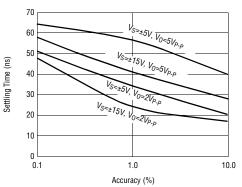
1MHz Harmonic Distortion vs Output Swing



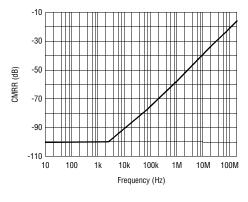
Ultra-Low Noise, Low Power, Wideband Amplifier

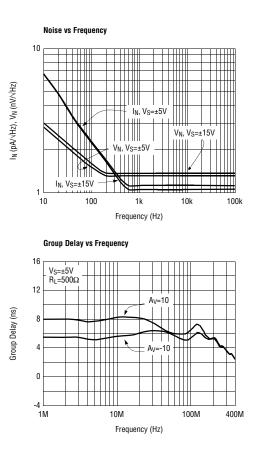


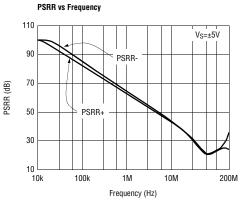


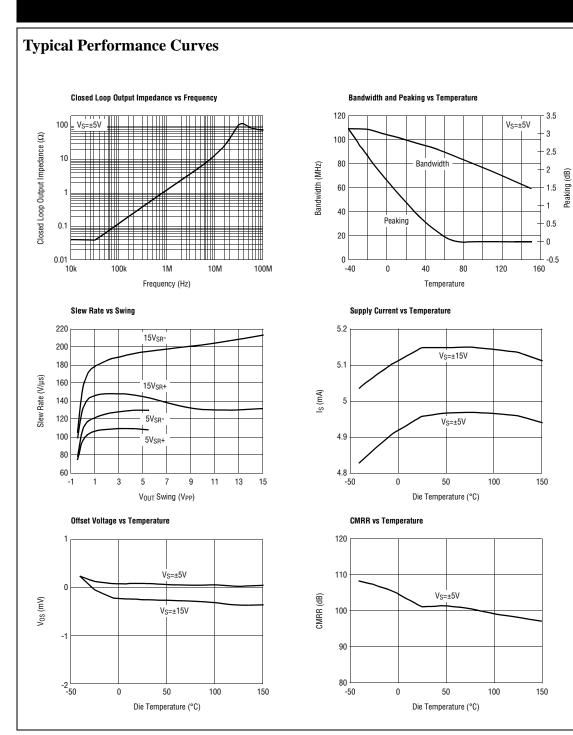








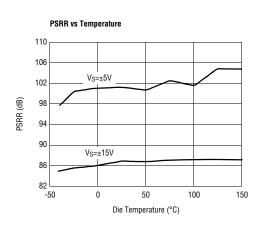




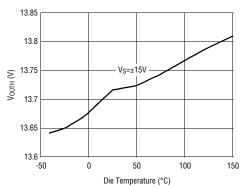
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Ultra-Low Noise, Low Power, Wideband Amplifier

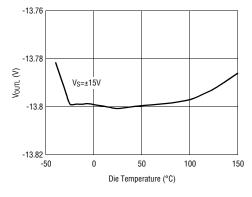
Typical Performance Curves



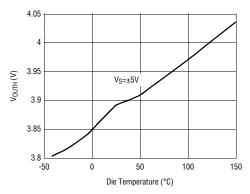
Positive Output Swing vs Temperature

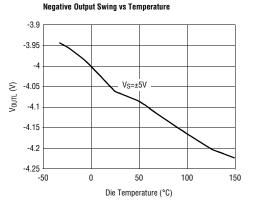






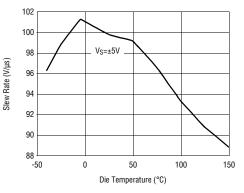
Positive Output Swing vs Temperature

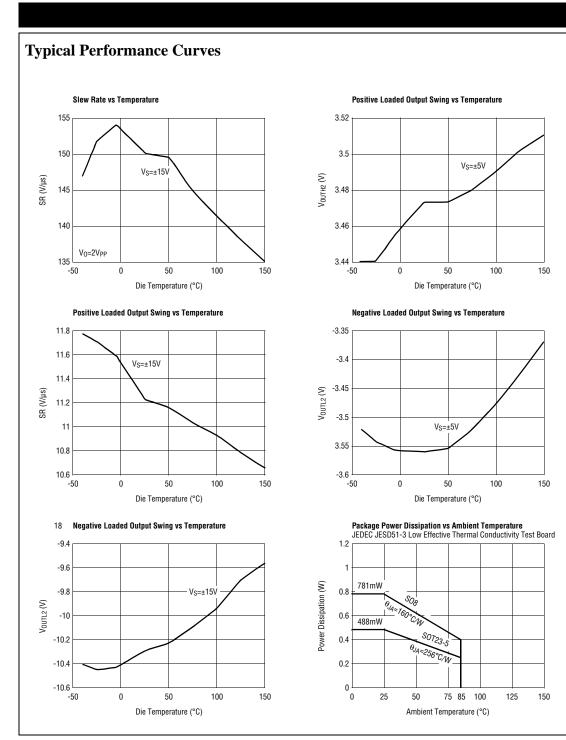




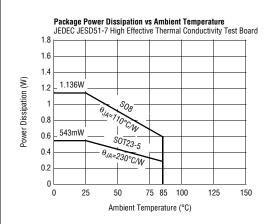


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Ultra-Low Noise, Low Power, Wideband Amplifier



EL2126C Ultra-Low Noise, Low Power, Wideband Amplifier

Pin Descriptions EL2126CW EL2126CS (5-Pin SOT-23) (8-Pin SO) Pin Name **Pin Function Equivalent Circuit** VOUT Output 1 6 Vs+ Vout Circuit 1 VS-2 4 Supply 3 3 VINA+ Input Vs+ VINH VIN-Vs-Circuit 2 4 2 VINA-Input Reference Circuit 2 5 7 VS+Supply

Applications Information

Product Description

The EL2126C is an ultra-low noise, wideband monolithic operational amplifier built on Elantec's proprietary high speed complementary bipolar process. It features $1.3nV/\sqrt{Hz}$ input voltage noise, 200µV typical offset voltage, and 73dB THD. It is intended for use in systems such as ultrasound imaging where very small signals are needed to be amplified. The EL2126C also has excellent DC specifications: 200µV V_{OS}, 22µA IB, 0.4µA I_{OS}, and 106dB CMRR. These specifications allow the EL2126C to be used in DC-sensitive applications such as difference amplifiers.

Gain-Bandwidth Product

The EL2126C has a gain-bandwidth product of 650MHz at ±5V. For gains less than 20, higher-order poles in the amplifier's transfer function contribute to even higher closed-loop bandwidths. For example, the EL2126C has a -3dB bandwidth of 100MHz at a gain of 10 and decreases to 33MHz at gain of 20. It is important to note that the extra bandwidth at lower gain does not come at the expenses of stability. Even though the EL2126C is designed for gain \geq 10. With external compensation, the device can also operate at lower gain settings. The RC network shown in Figure 1 reduces the feedback gain at high frequency and thus maintains the amplifier stability. R values must be less than RF divided by 9 and 1 divided by 2π RC must be less than 200MHz.

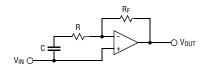


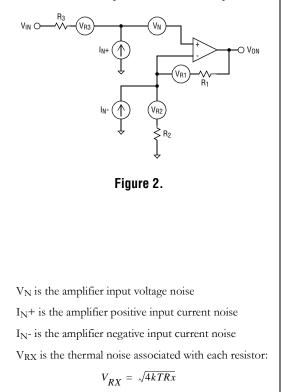
Figure 1.

Choice of Feedback Resistor, RF

The feedback resistor forms a pole with the input capacitance. As this pole becomes larger, phase margin is reduced. This increases ringing in the time domain and peaking in the frequency domain. Therefore, RF has some maximum value which should not be exceeded for optimum performance. If a large value of RF must be used, a small capacitor in the few pF range in parallel with RF can help to reduce this ringing and peaking at the expense of reducing the bandwidth. Frequency response curves for various RF values are shown in the typical performance curves section of this data sheet.

Noise Calculations

The primary application for the EL2126C is to amplify very small signals. To maintain the proper signal-tonoise ratio, it is essential to minimize noise contribution from the amplifier. Figure 2 below shows all the noise sources for all the components around the amplifier.



where:

- k is Boltzmann's constant = 1.380658×10^{-23}
- T is temperature in degrees Kelvin (273+ °C)

The total noise due to the amplifier seen at the output of the amplifier can be calculated by using the following equation:

$$V_{ON} = \sqrt{BW} \times \sqrt{\left(VN^2 \times \left(1 + \frac{R_1}{R_2}\right)^2 + IN^{-2} \times R_1^2 + IN^{+2} \times R_3^2 \times \left(1 + \frac{R_1}{R_2}\right)^2 + 4 \times K \times T \times R_1 + 4 \times K \times T \times R_2 \times \left(\frac{R_1}{R_2}\right)^2 + 4 \times K \times T \times R_3 \times \left(1 + \frac{R_1}{R_2}\right)^2\right)}$$

As the above equation shows, to keep noise at a minimum, small resistor values should be used. At higher amplifier gain configuration where R_2 is reduced, the noise due to IN-, R_2 , and R_1 decreases and the noise caused by IN+, VN, and R_3 starts to dominate. Because noise is summed in a root-mean-squares method, noise sources smaller than 25% of the largest noise source can be ignored. This can greatly simplify the formula and make noise calculation much easier to calculate.

Output Drive Capability

The EL2126C is designed to drive low impedance load. It can easily drive $6V_{P-P}$ signal into a 100 Ω load. This high output drive capability makes the EL2126C an ideal choice for RF, IF, and video applications. Furthermore, the EL2126C is current-limited at the output, allowing it to withstand momentary short to ground. However, the power dissipation with output-shorted cannot exceed the power dissipation capability of the package.

Driving Cables and Capacitive Loads

Although the EL2126C is designed to drive low impedance load, capacitive loads will decreases the amplifier's phase margin. As shown in the performance curves, capacitive load can result in peaking, overshoot and possible oscillation. For optimum AC performance, capacitive loads should be reduced as much as possible or isolated with a series resistor between 5Ω to 20Ω . When driving coaxial cables, double termination is always recommended for reflection-free performance. When properly terminated, the capacitance of the coaxial cable will not add to the capacitive load seen by the amplifier.

Power Supply Bypassing And Printed Circuit Board Layout

As with any high frequency devices, good printed circuit board layout is essential for optimum performance.

Ground plane construction is highly recommended. Lead lengths should be kept as short as possible. The power supply pins must be closely bypassed to reduce the risk of oscillation. The combination of a 4.7 μ F tantalum capacitor in parallel with 0.1 μ F ceramic capacitor has been proven to work well when placed at each supply pin. For single supply operation, where pin 4 (V_S-) is connected to the ground plane, a single 4.7 μ F tantalum capacitor in parallel with a 0.1 μ F ceramic capacitor across pins 7 (V_S+) and pin 4 (V_S-) will suffice.

For good AC performance, parasitic capacitance should be kept to a minimum. Ground plane construction again should be used. Small chip resistors are recommended to minimize series inductance. Use of sockets should be avoided since they add parasitic inductance and capacitance which will result in additional peaking and overshoot.

Supply Voltage Range and Single Supply Operation

The EL2126C has been designed to operate with supply voltage range of ± 2.5 V to ± 15 V. With a single supply, the EL2126C will operate from +5V to +30V. Pins 4 and 7 are the power supply pins. The positive power supply is connected to pin 7. When used in single supply mode, pin 4 is connected to ground. When used in dual supply mode, the negative power supply is connected to pin 4.

As the power supply voltage decreases from +30V to +5V, it becomes necessary to pay special attention to the input voltage range. The EL2126C has an input voltage range of 0.4V from the negative supply to 1.2V from the positive supply. So, for example, on a single +5V supply, the EL2126C has an input voltage range which spans from 0.4V to 3.8V. The output range of the EL2126C is also quite large, on a +5V supply, it swings from 0.4V to 3.8V.

EL2126C Ultra-Low Noise, Low Power, Wideband Amplifier

Effective May 15, 2002, Elantec, a leader in high performance analog products, is now a part of Intersil Corporation.

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